### February 8, 2012 IRS2113MPBF HIGH- AND LOW-SIDE DRIVER

#### Features

- Floating channel designed for bootstrap operation
- Fully operational to +600 V
- Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout for both channels
- 3.3 V input logic compatible
- Separate logic supply range from 3.3 V to 20 V
- Logic and power ground ±5 V offset
- CMOS Schmitt-triggered inputs with pull-down
- Cycle by cycle edge-triggered shutdown logic
- Matched propagation delay for both channels
- Output in phase with inputs
- Leadfree, RoHS Compliant

#### Description

The IRS2113MPBF is a high voltage, high speed power MOSFET and IGBT drivers with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 V.

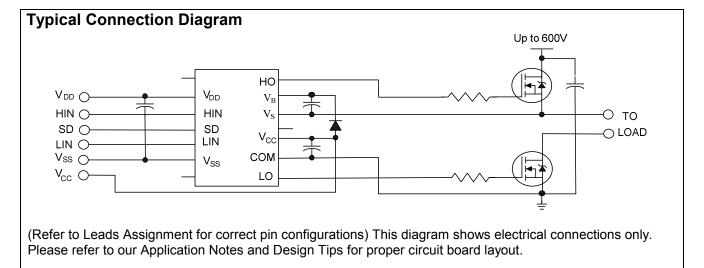
#### **Product Summary**

Topology	2 channels
V <sub>OFFSET</sub>	600 V max
V <sub>OUT</sub>	10 V – 20 V
l₀₊ & l ₀₋ (typical)	2.5 A / 2.5 A
t <sub>on</sub> & t <sub>off</sub> (typical)	130 ns & 120 ns
Delay Matching	20 ns max

#### Package Option



MLPQ4x4-16-Lead (without 2 leads)



### **Qualification Information<sup>†</sup>**

Qualification Level		Industrial <sup>††</sup> (per JEDEC JESD 47)			
		Comments: This IC has passed JEDEC's Industrial			
			nsumer qualification level is		
		granted by extension of	f the higher Industrial level.		
			MSL2 <sup>†††</sup>		
Moisture Sensitivity Level		MLPQ4x4 14L	(per IPC/JEDEC J-STD-		
			020)		
	Machine Model	Class A (+/-200V)			
		(per JEDEC sta	andard JESD22-A115)		
ESD	Human Rady Madal	Class 1B (+/-1000V)			
230	Human Body Model	(per EIA/JEDEC standard EIA/JESD22-A114)			
	Charged Davies Medal	Class III (+/-1000V)			
Charged Device Model		(per JEDEC standard JESD22-C101)			
IC Latab Un Taat		Class II, Level A			
IC Latch-Up Test		(per JESD78A)			
RoHS Compliant		Yes			

† Qualification standards can be found at International Rectifier's web site <u>http://www.irf.com/</u>

- ++ Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

#### **Absolute Maximum Ratings**

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V <sub>B</sub>	High-side floating supply voltage	-0.3	625	
Vs	High-side floating supply offset voltage	V <sub>B</sub> - 20	V <sub>B</sub> + 0.3	
V <sub>HO</sub>	High-side floating output voltage	V <sub>S</sub> -0.3	V <sub>B</sub> + 0.3	
V <sub>CC</sub>	Low-side fixed supply voltage	-0.3	25	V
V <sub>LO</sub>	Low-side output voltage	-0.3	V <sub>CC</sub> + 0.3	· ·
V <sub>DD</sub>	Logic supply voltage	-0.3	V <sub>SS</sub> + 20 (†)	
V <sub>SS</sub>	Logic supply offset voltage	V <sub>CC</sub> - 20	V <sub>CC</sub> + 0.3	
V <sub>IN</sub>	Logic input voltage (HIN, LIN & SD)	V <sub>SS</sub> -0.3	V <sub>DD</sub> + 0.3	
dV <sub>S</sub> /dt	Allowable offset supply voltage transient (Fig. 2)	—	50	V/ns
PD	Package power dissipation @ TA $\leq 25^{\circ}$ C	—	2.08	W
Rth <sub>JA</sub>	Thermal resistance, junction to ambient	—	36	°C/W
TJ	Junction temperature	—	150	
Ts	Storage temperature	-55	150	°C
TL	Lead temperature (soldering, 10 seconds)	—	300	

† All supplies are fully tested at 25 V, and an internal 20 V clamp exists for each supply.

#### **Recommended Operating Conditions**

The input/output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The  $V_s$  and  $V_{ss}$  offset rating are tested with all supplies biased at 15 V differential.

Symbol	Definition	Min.	Max.	Units
VB	High-side floating supply absolute voltage	V <sub>s</sub> +10	V <sub>S</sub> +20	
Vs	High-side floating supply offset voltage	†	600	
V <sub>HO</sub>	High-side floating output voltage	Vs	V <sub>B</sub>	
V <sub>CC</sub>	Low-side fixed supply voltage	10	20	V
V <sub>LO</sub>	Low-side output voltage	0	V <sub>cc</sub>	v
V <sub>DD</sub>	Logic supply voltage	V <sub>SS</sub> + 3	V <sub>SS</sub> + 20	
V <sub>SS</sub>	Logic ground offset voltage	-5 (††)	5	
V <sub>IN</sub>	Logic input voltage (HIN, LIN & SD)	V <sub>SS</sub>	V <sub>DD</sub>	
T <sub>A</sub>	Ambient temperature	-40	125	°C

 $\label{eq:logicoperational for V_S of -4 V to +500 V. Logic state held for V_S of -4 V to - V_{BS.} (Please refer to the Design Tip DT97 -3 for more details).$ 

†† When  $V_{DD} < 5 V$ , the minimum  $V_{SS}$  offset is limited to  $-V_{DD}$ .

#### **Static Electrical Characteristics**

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ,  $V_{DD}$ ) = 15 V,  $T_A$  = 25°C and  $V_{SS}$  = COM unless otherwise specified. The  $V_{IL}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to  $V_{SS}$  and are applicable to all three logic input leads: HIN, LIN and SD. The  $V_{0}$ , and  $I_{0}$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

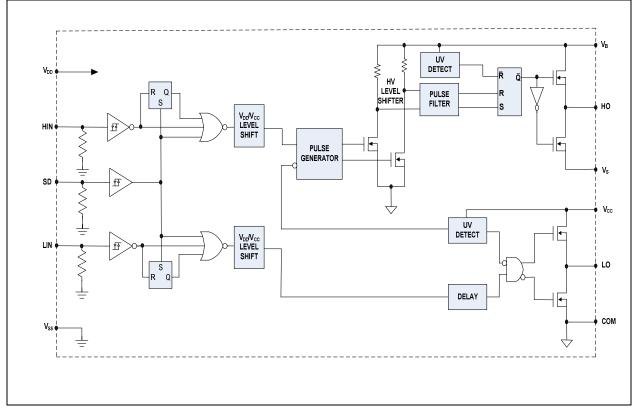
Symbol	Definition	Min	Тур	Мах	Units	Test Conditions
V <sub>IH</sub>	Logic "1" input voltage	9.5	—			
V <sub>IL</sub>	Logic "0" input voltage	—	—	6.0	V	
V <sub>OH</sub>	High level output voltage, V <sub>BIAS</sub> - V <sub>O</sub>	—	—	1.4	v	I <sub>0</sub> = 0 A
V <sub>OL</sub>	Low level output voltage, V <sub>o</sub>	_	_	0.15		l <sub>o</sub> = 20 mA
I <sub>LK</sub>	Offset supply leakage current	—		50		$V_{\rm B} = V_{\rm S} = 600$
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> supply current	—	125	230		
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> supply current	_	180	340	μA	V <sub>IN</sub> = 0 V or V <sub>DD</sub>
I <sub>QDD</sub>	Quiescent V <sub>DD</sub> supply current – 15		30		• 00	
I <sub>IN+</sub>	Logic "1" input bias current	_	20	40		$V_{IN} = V_{DD}$
I <sub>IN-</sub>	Logic "0" input bias current	—	—	5.0		$V_{IN} = 0 V$
V <sub>BSUV+</sub>	$V_{BS}$ supply undervoltage positive going threshold	7.5	8.6	9.7		
V <sub>BSUV-</sub>	V <sub>BS</sub> supply undervoltage negative going threshold	7.0	8.2	9.4	V	
V <sub>CCUV+</sub>	V <sub>CC</sub> supply undervoltage positive going threshold	7.4	8.5	9.6	v	
V <sub>CCUV-</sub>	V <sub>CC</sub> supply undervoltage negative going threshold	7.0	8.2	9.4		
I <sub>O+</sub>	Output high short circuit pulsed current	2.0	2.5		А	$V_{O} = 0 V,$ $V_{IN} = V_{DD}$ $PW \le 10 \text{ us}$
I <sub>O-</sub>	Output low short circuit pulsed current	2.0	2.5		A	$V_{O} = 15 V,$ $V_{IN} = 0 V$ $PW \le 10 us$

#### **Dynamic Electrical Characteristics**

 $V_{BIAS}$  (V<sub>CC</sub>, V<sub>BS</sub>, V<sub>DD</sub>) = 15 V, C<sub>L</sub> = 1000 pF, T<sub>A</sub> = 25°C and V<sub>SS</sub> = COM unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Fig. 3.

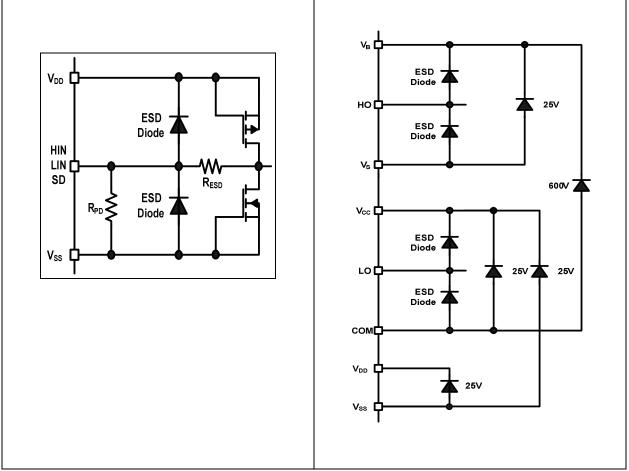
Symbol	Definition	Min	Тур	Max	Units	Test Conditions
t <sub>on</sub>	Turn-on propagation delay		130	200		$V_{\rm S}$ = 0 V
t <sub>off</sub>	Turn-off propagation delay		120	190		V <sub>S</sub> = 600 V
t <sub>sd</sub>	Shutdown propagation delay		130	160	ns	v <sub>s</sub> = 000 v
t <sub>r</sub>	Turn-on rise time		25	35	115	
t <sub>f</sub>	Turn-off fall time	—	17	25		
MT	Delay matching, HS & LS turn on/off		_	20		

### Functional Block Diagram



# International **tor** Rectifier

## Input/Output Pin Equivalent Circuit Diagrams

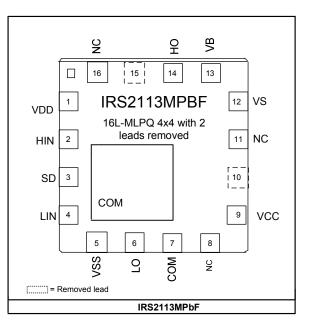


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### Lead Definitions

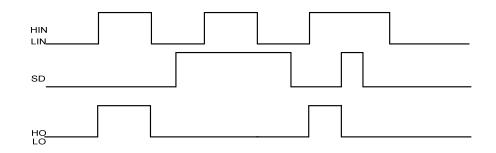
PIN	Symbol	Description
1	V <sub>DD</sub>	Logic supply
2	HIN	Logic input for high-side gate driver output (HO), in phase
3	SD	Logic input for shutdown
4	LIN	Logic input for low-side gate driver output (LO), in phase
5	$V_{SS}$	Logic ground
6	LO	Low-side gate drive output
7	СОМ	Low-side return
8	NC	No Connection
9	V <sub>CC</sub>	Low-side supply
10	NC	No Connection (pin removed)
11	NC	No Connection
12	Vs	High-side floating supply return
13	V <sub>B</sub>	High-side floating supply
14	НО	High-side gate drive output
15	NC	No Connection (pin removed)
16	NC	No Connection

## Lead Assignments





#### **Application Information and Additional Details**





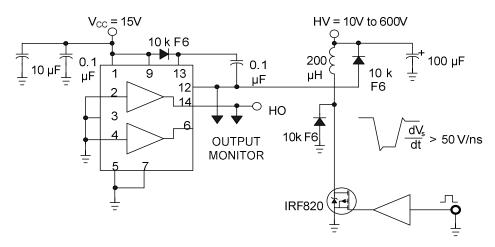


Figure 2: Floating Supply Voltage Transient Test Circuit

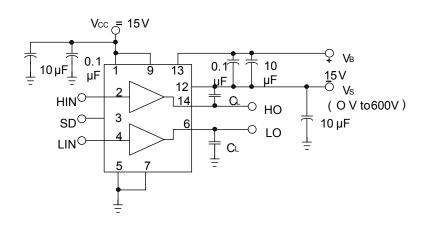


Figure 3: Switching Time Test Circuit

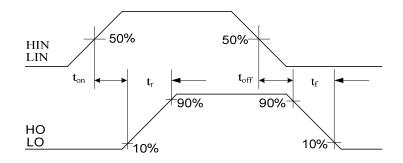


Figure 4: Switching Time Waveform Definitions

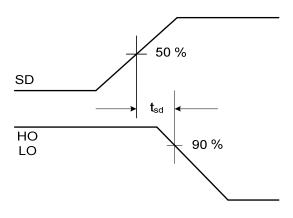


Figure 5: Shutdown Waveform Definitions

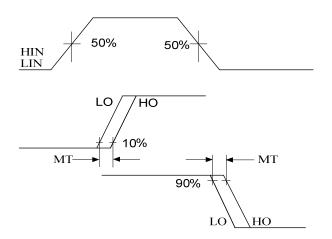
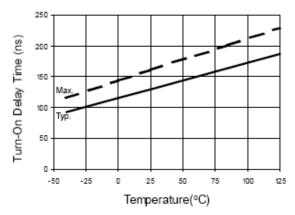


Figure 6: Delay Matching Waveform Definitions

### **Parameter Temperature Trends**



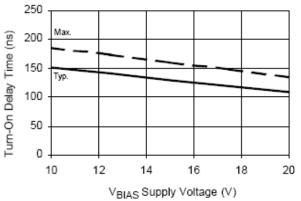


Figure 7A. Turn-On Time vs. Temperature

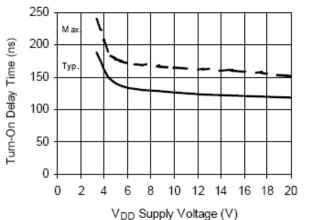
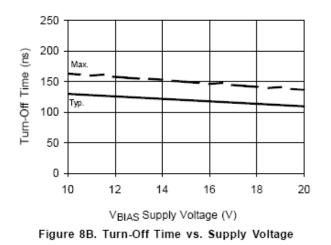


Figure 7C. Turn-On Time vs. VDD Supply Voltage





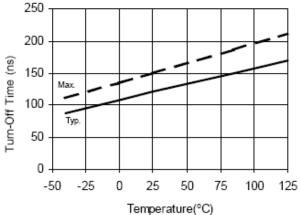


Figure 8A. Turn-Off Time vs. Temperature

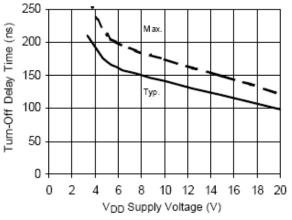


Figure 8C. Turn-Off Time vs. Vod Supply Voltage

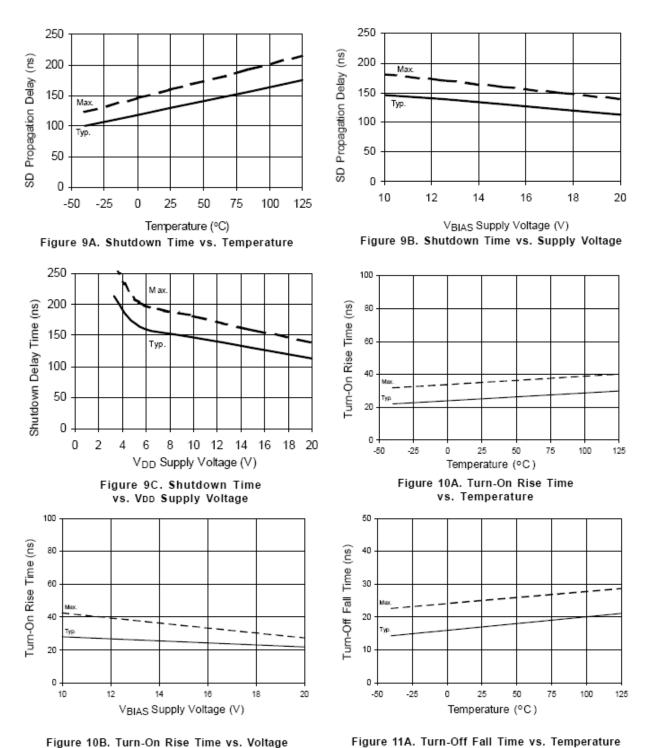
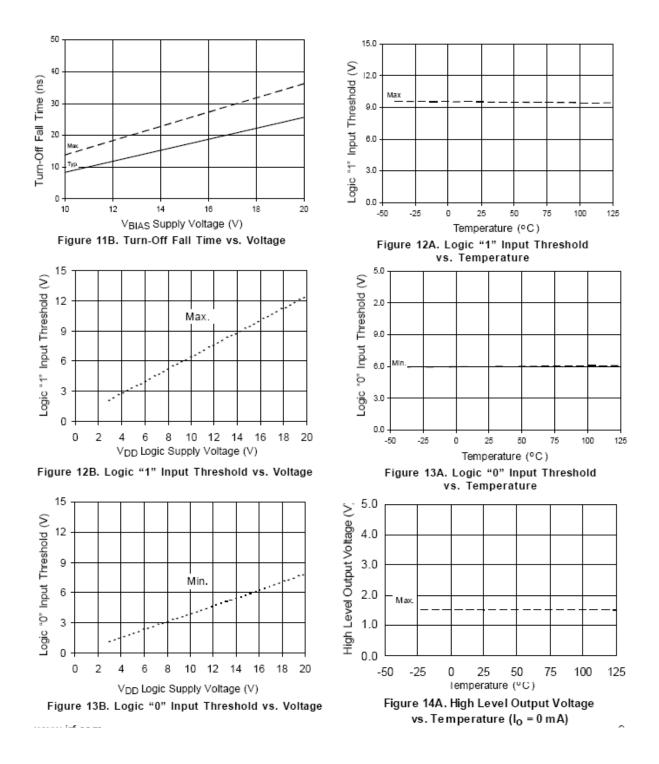
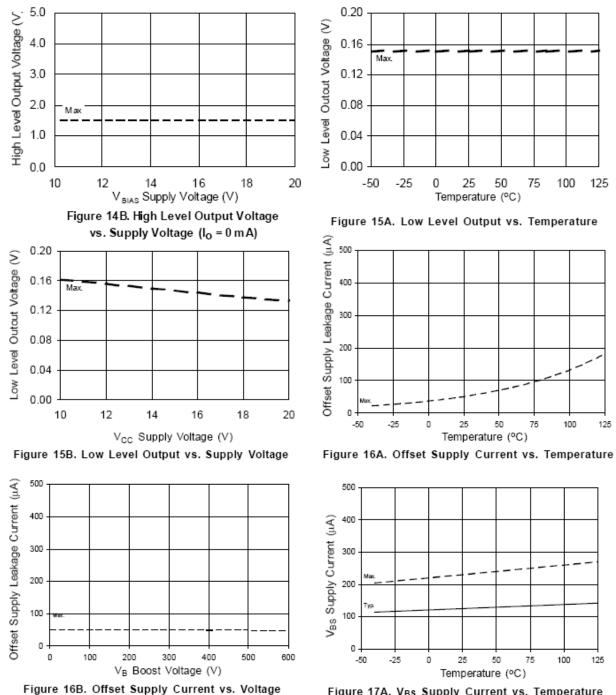
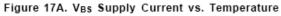


Figure 11A. Turn-Off Fall Time vs. Temperature

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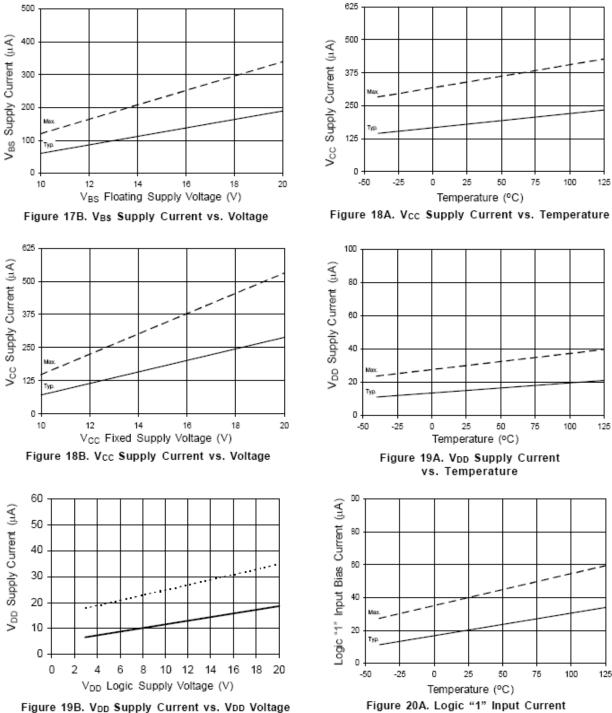
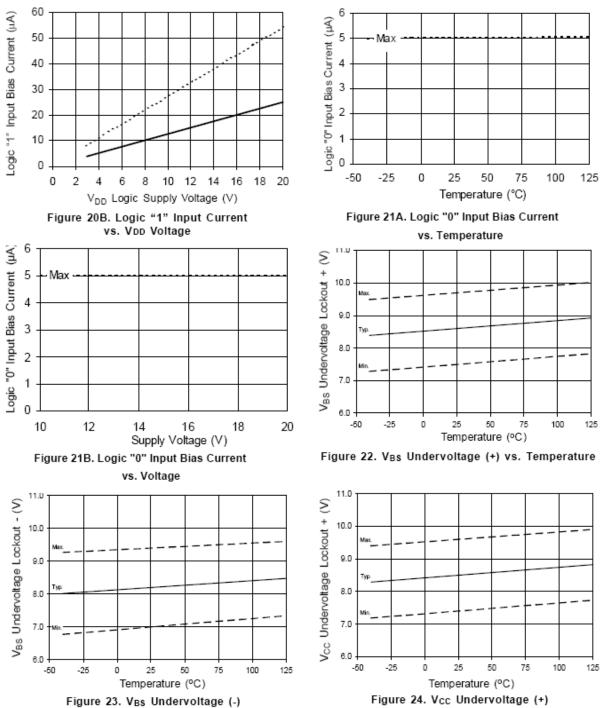
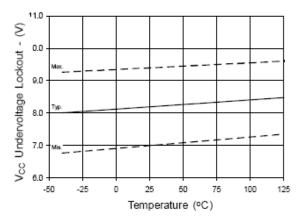


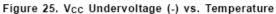
Figure 20A. Logic "1" Input Current vs. Temperature



vs. Temperature

vs. Temperature





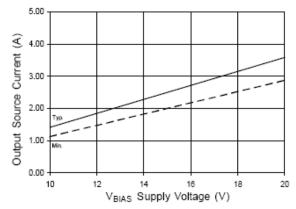


Figure 26B. Output Source Current vs. Voltage

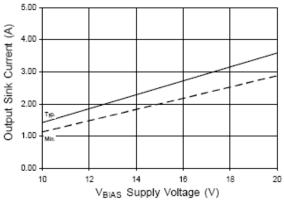


Figure 27B. Output Sink Current vs. Voltage

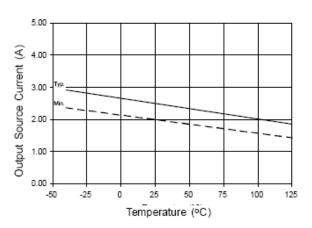


Figure 26A. Output Source Current vs. Temperature

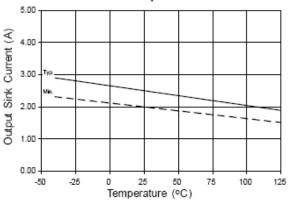
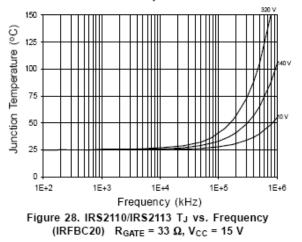
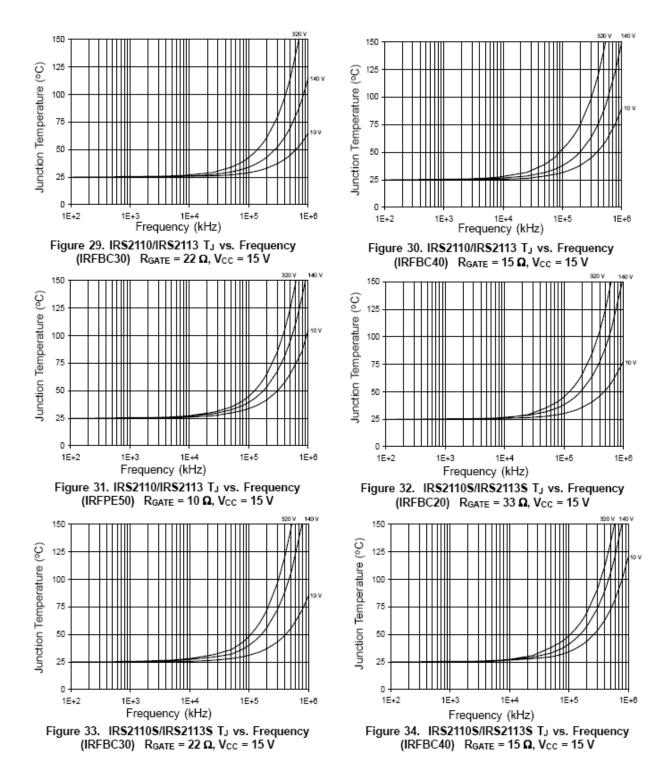
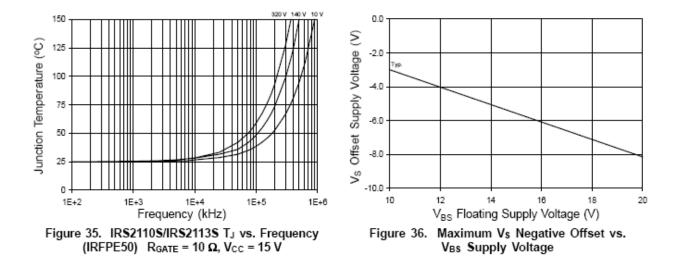


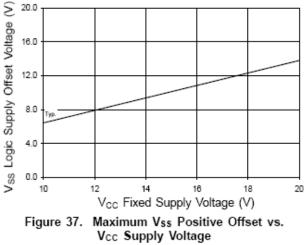
Figure 27A. Output Sink Current vs. Temperature



# International

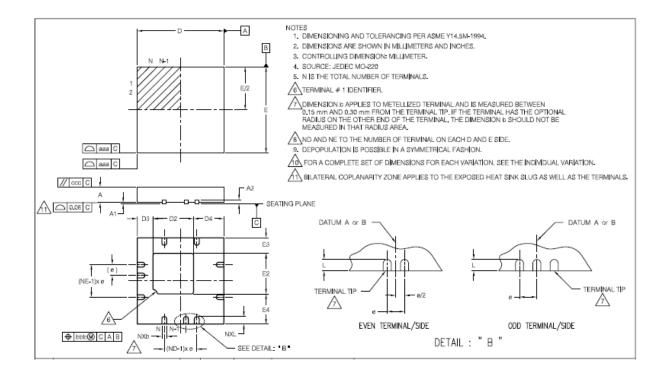






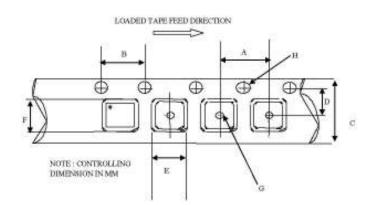
# International

### Package Details: MLPQ 4x4 -16L



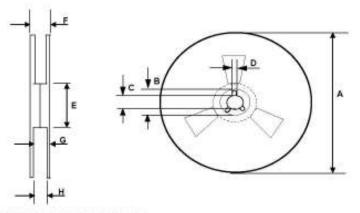
S Y M		VGGD-10				
М В О L	M	ILLIMETE	RS			
Ľ	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	.032	.035	-039
A1	0.00	0.02	0.05	.000	-0008	.0019
A3		0.20 REF			.008 REF	
b	0.18	0.25	0.30	.007	.010	.012
D2	1.78	1.88	1.98	.070	.074	.078
D3		0.73 REF	-	.029 REF		
D4		1.40 REF	-	.055 REF		
D		4.00 BSC	>	.157 BSC		
E		4.00 BSC	>	157 BSC		
E4		1.40 REF	-	.055 REF		
E3	0.73 REF				.029 REF	
E2	1.78	1.88	1.98	.070	.074	.078
L	0.30	0.40	0.50	.012	.016	.020
е	0.50 PITCH				20 PITCI	H
N		16			16	
ND	4			4		
NE	4			4		
aaa	0.15			.0059		
bbb	0.10				.0039	
CCC		0.10			.0039	
ddd		0.05			.0019	

### Tape and Reel Details: MLPQ 4x4



CARRIER TAPE DIMENSION FOR MLPQ4X4V

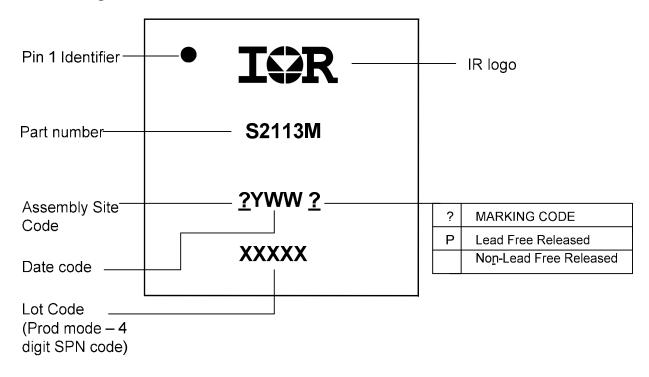
Sec. a	Mo	tric	Imp	erial
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.358
8	3.90	4.10	0.154	0.161
Ċ	11.70	12.30	0.461	0.484
D	5.45	5.55	0.215	0.219
E	4.25	4.45	0.168	0.176
F	4.25	4.45	0.168	0.176
G	1.50	n/a	0.069	n/a
н	1.50	1.60	0.069	0.063



REEL	DIMENSIONS	FOR MLP	Q4X4V

	Metric		Imperial		
Code	Min	Max	Min	Max	
A	329.60	330.25	12.976	13.001	
B	20,95	21.45	0.824	0.844	
C	12.80	13.20	0.503	0.519	
D	1.96	2.45	0.767	0.096	
E	98.00	102.00	3.858	4.015	
F.	n/a	18.40	n/a	0.724	
G	14.50	17.10	0.570	0.673	
н	12.40	14.40	0.488	0.566	

#### **Part Marking Information:**



#### **Ordering Information**

		Standard	Pack	Complete Dort Number	
Base Part Number	Package Type	Form	Quantity	Complete Part Number	
		Tube/Bulk	92	IRS2113MPBF	
IRS2113	MLPQ 4x4-16L	Tape and Reel	3,000	IRS2113MTRPBF	

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### **Revision History**

Date	Comment
09/24/09	Initial conversion from SO package style data sheet
03/24/2010	Included qual info page
08/08/2011	Update the package details
02/08/2012	Update pin assignment drawing

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